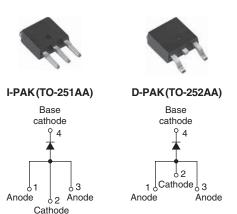


VS-10UT10

Vishay Semiconductors

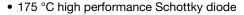
High Performance Generation 5.0 Schottky Rectifier, 10 A



VS-10WT10FN

PRODUCT SUMMARY				
Package	I-PAK (TO-251AA),			
1 dokago	D-PAK (TO-252AA)			
I _{F(AV)}	10 A			
V_{R}	100 V			
V _F at I _F	0.66 V			
I _{RM} max.	4 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	54 mJ			

FEATURES





- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_B trade off for high efficiency

RoHS

- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47

APPLICATIONS

- High efficiency SMPS
- · High frequency switching
- · Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V _{RRM}		100	V			
V _F	10 Apk, T _J = 125 °C (typical)	0.615	V			
T _J	Range	- 55 to 175	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-10UT10 VS-10WT10FN	UNITS
Maximum DC reverse voltage	V_{R}	T _J = 25 °C	100	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 159 °C, rectangular waveform		10	А
Maximum peak one cycle I _F	I _{FSM} 5 μs sine or 3 μs rect. pulse 10 ms sine or 6 ms rect. pulse	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	610	А
		V _{RRM} applied ⁽¹⁾	110	A	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 12 mH		54	mJ
Repetitive avalanche current	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$. I_{AS} at $T_J max$. as a function of time pulse (see fig. 8)		I _{AS} at T _J max.	А

Note

(1) Measured connecting 2 anode pins



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop	V _{FM} ⁽¹⁾⁽²⁾	5 A		0.630	-	- V
		10 A	T _J = 25 °C	0.735	0.810	
		20 A		0.840	0.890	
		5 A		0.530	-	
		10 A	T _J = 125 °C	0.615	0.660	
		20 A		0.730	0.770	
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Dated V	-	50	μΑ
		T _J = 125 °C	V _R = Rated V _R	-	4	mA
Junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		400	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Notes

- $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %
- (2) Only 1 anode pin connected

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}		0.3	C/VV
Approximate weight			0.3	g
Approximate weight			0.01	OZ.
Madisarda isa		Case style I-PAK	10U	T10
Marking device		Case style D-PAK	10WT10FN	

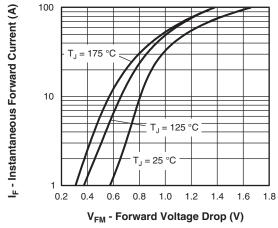


Fig. 1 - Maximum Forward Voltage Drop Characteristics

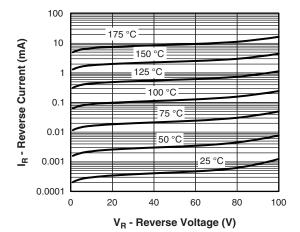


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

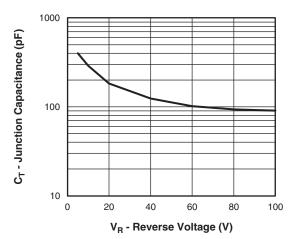


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

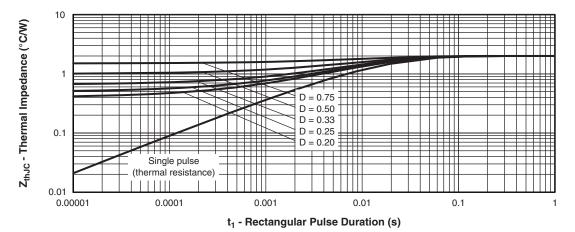


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

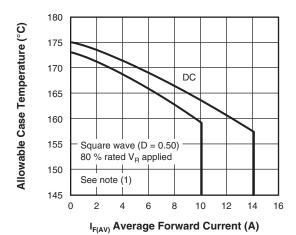


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

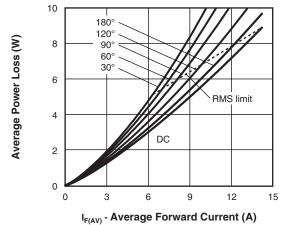
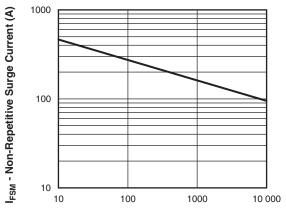


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \text{ (1 - D); } I_R \text{ (2 - D);$

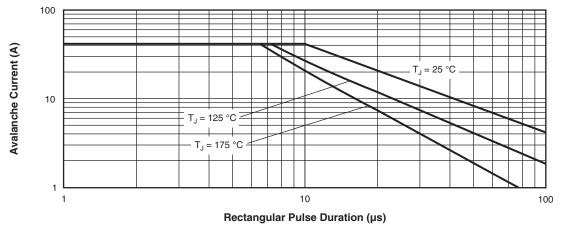


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

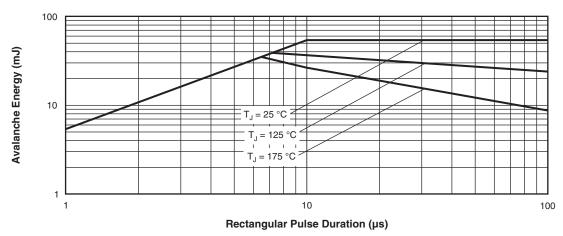
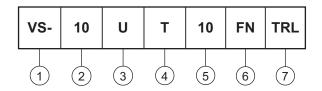


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (10 A)

3 - Package:

• U = I-PAK

• W = D-PAK

4 - T = Trench

5 - Voltage code (100 V)

TO-252AA (D-PAK)

7 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

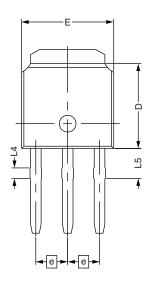
• TRR = Tape and reel (right oriented)

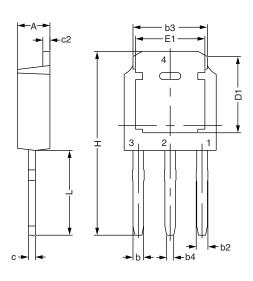
LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Diffierisions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95026			



I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS			
STWIBOL	MIN.	NOM.	MAX.	
E	6.40	6.60	6.70	
L	3.98	4.13	4.28	
L4	0.66	0.76	0.86	
L5	1.96	2.16	2.36	
D	6.00	6.10	6.20	
Н	11.05	11.25	11.45	
b	0.64	0.76	0.88	
b2	0.77	0.84	1.14	
b3	5.21	5.34	5.46	
b4	0.41	0.51	0.61	
е	2.286 BSC			
Α	2.20	2.30	2.38	
С	0.40	0.50	0.60	
c2	0.40	0.50	0.60	
D1	5.30	-	-	
E1	4.40	-	-	



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Vishay

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